

# STD6NF10 STU6NF10

# N-channel 100 V, 0.22 Ω 6 A, DPAK, IPAK low gate charge STripFET™ Power MOSFET

### Features

Туре	V <sub>DSS</sub>	R <sub>DS(on)</sub> max	I <sub>D</sub>
STD6NF10	100 V	< 0.250 Ω	6 A
STU6NF10	100 V	< 0.250 Ω	6 A

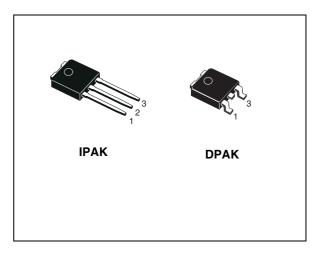
- Exceptional dv/dt capability
- 100% avalanche tested

## Application

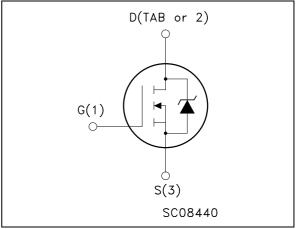
Switching applications

### Description

This Power MOSFET series realized with STMicroelectronics unique STripFET process has specifically been designed to minimize input capacitance and gate charge. It is therefore suitable as primary switch in advanced highefficiency, high-frequency isolated DC-DC converters for telecom and computer applications. It is also intended for any applications with low gate drive requirements.



### Figure 1. Internal schematic diagram



### Table 1. Device summary

Order codes	Marking	Package	Packaging
STD6NF10T4	D6NF10	DPAK	Tape and reel
STU6NF10	6NF10	IPAK	Tube

# Contents

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# 1 Electrical ratings

Symbol	Parameter	Value	Unit
V <sub>DS</sub>	Drain-source voltage ( $V_{GS} = 0$ )	100	V
V <sub>GS</sub>	Gate- source voltage	± 20	V
۱ <sub>D</sub>	Drain current (continuous) at T <sub>C</sub> = 25 °C	6	А
۱ <sub>D</sub>	Drain current (continuous) at T <sub>C</sub> = 100 °C	4	А
I <sub>DM</sub> <sup>(1)</sup>	Drain current (pulsed)	24	А
P <sub>tot</sub>	Total dissipation at $T_C = 25 \ ^{\circ}C$	30	W
	Derating factor	0.2	W/°C
dv/dt <sup>(2)</sup>	Peak diode recovery voltage slope	40	V/ns
E <sub>AS</sub> <sup>(3)</sup>	Single pulse avalanche energy	200	mJ
T <sub>stg</sub>	Storage temperature	-65 to 175	°C
Тj	Max. operating junction temperature	-05 10 175	U

1. Pulse width limited by safe operating area.

2. I\_{SD} ~\leq~ 6 A, di/dt  $~\leq$  300 A/µs, V\_{DD} ~\leq~ V\_{(BR)DSS}, Tj ~ $\leq$   $T_{JMAX}$ 

3. Starting  $T_j$  = 25 °C,  $I_D$  = 3 A,  $V_{DD}$  = 50 V

Symbol	Symbol Parameter		Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	5	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-ambient max	100	°C/W
TJ	Maximum lead temperature for soldering purpose	300	°C

# 2 Electrical characteristics

(T<sub>CASE</sub> = 25 °C unless otherwise specified)

	On/on states					
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>(BR)DSS</sub>	Drain-source breakdown voltage	$I_D = 250 \ \mu A, \ V_{GS} = 0$	100			V
I <sub>DSS</sub>	Zero gate voltage drain current (V <sub>GS</sub> = 0)	$V_{DS}$ = max rating $V_{DS}$ =max rating, $T_{C}$ = 125 °C			1 10	μΑ μΑ
I <sub>GSS</sub>	Gate-body leakage current (V <sub>DS</sub> = 0)	$V_{GS} = \pm 20 V$			±100	nA
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{DS}=V_{GS},\ I_{D}=250\ \mu A$	2		4	V
R <sub>DS(on)</sub>	Static drain-source on resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$		0.22	0.25	Ω

### Table 4. On/off states

#### Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
9 <sub>fs</sub> <sup>(1)</sup>	Forward transconductance	$V_{DS} = > I_{D(on)} x$ R <sub>DS(on)max</sub> , I <sub>D</sub> = 3A		34		S
C <sub>iss</sub> C <sub>oss</sub> C <sub>rss</sub>	Input capacitance Output capacitance Reverse transfer capacitance	V <sub>DS</sub> = 25 V, f = 1 MHz, V <sub>GS</sub> = 0		280 45 20		pF pF pF
t <sub>d(on)</sub> t <sub>r</sub> t <sub>d(off)</sub> t <sub>f</sub>	Turn-on delay time Rise time Turn-off delay time Fall time	$V_{DD} = 50 \text{ V}, I_D = 3 \text{ A}$ $R_G = 4.7 \Omega, V_{GS} = 10 \text{ V}$ (see <i>Figure 13</i> )		6 10 20 3		ns ns ns ns
Q <sub>g</sub> Q <sub>gs</sub> Q <sub>gd</sub>	Total gate charge Gate-source charge Gate-drain charge	$V_{DD} = 80 \text{ V}, \text{ I}_{D} = 6 \text{ A},$ $V_{GS} = 10 \text{ V}, \text{ R}_{G} = 4.7 \Omega$ (see <i>Figure 14</i> )		10 2.5 4	14	nC nC nC

1. Pulsed: Pulse duration = 300  $\mu$ s, duty cycle 1.5%.



Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>SD</sub> I <sub>SDM</sub> <sup>(1)</sup>	Source-drain current Source-drain current (pulsed)				6 24	A A
V <sub>SD</sub> <sup>(2)</sup>	Forward on voltage	I <sub>SD</sub> = 6 A, V <sub>GS</sub> = 0			1.3	V
t <sub>rr</sub> Q <sub>rr</sub> I <sub>RRM</sub>	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD} = 6 \text{ A, di/dt} = 100 \text{ A/}\mu\text{s,}$ $V_{DD} = 10 \text{ V, } \text{T}_{j} = 150 \text{ °C}$ (see <i>Figure 15</i> )		70 175 5		ns nC A

 Table 6.
 Source drain diode

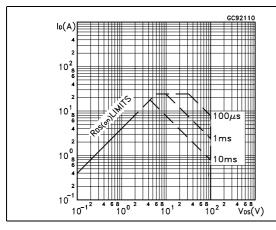
1. Pulse width limited by safe operating area.

2. Pulsed: Pulse duration = 300  $\mu$ s, duty cycle 1.5%

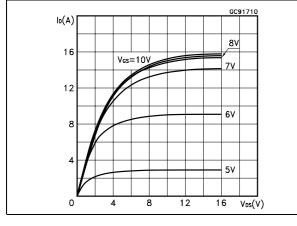


## 2.1 Electrical characteristics (curves)

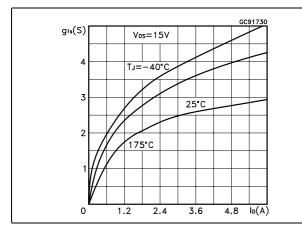
### Figure 2. Safe operating area

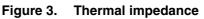


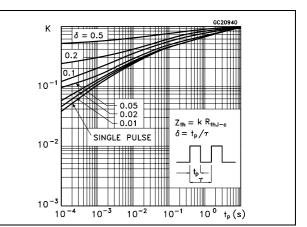


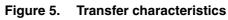












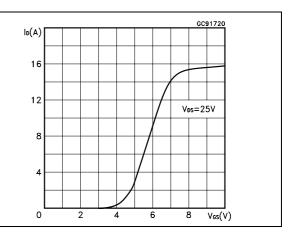
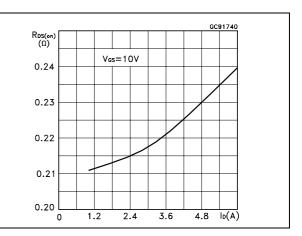
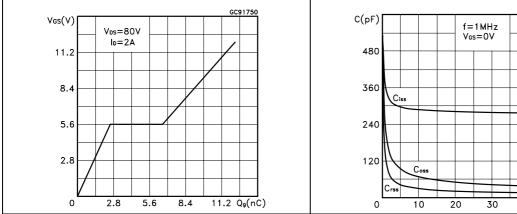


Figure 7. Static drain-source on resistance

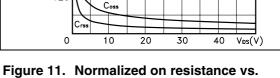


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#### Gate charge vs. gate-source voltage Figure 9. **Capacitance variations** Figure 8.

Figure 10. Normalized gate threshold voltage vs. temperature



temperature

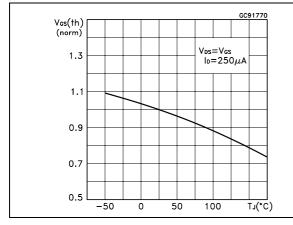
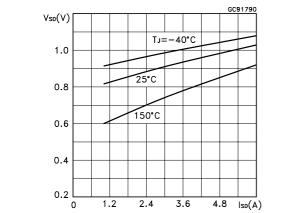
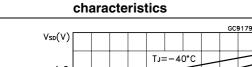
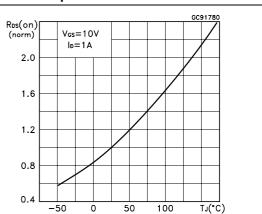


Figure 12. Source-drain diode forward characteristics







# 3 Test circuits

Figure 13. Switching times test circuit for resistive load

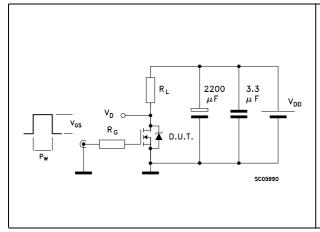
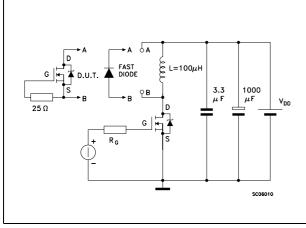


Figure 15. Test circuit for inductive load switching and diode recovery times





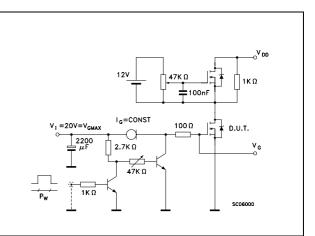
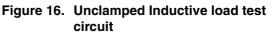


Figure 14. Gate charge test circuit



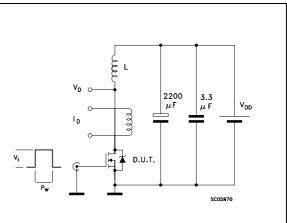
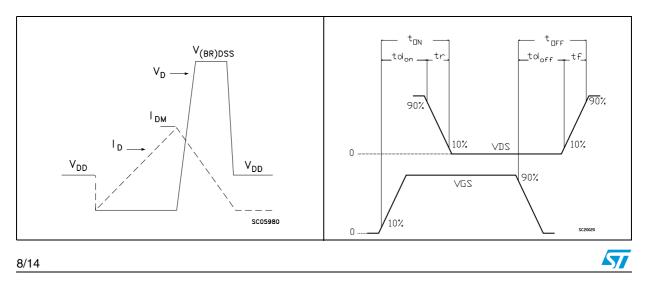


Figure 18. Switching time waveform

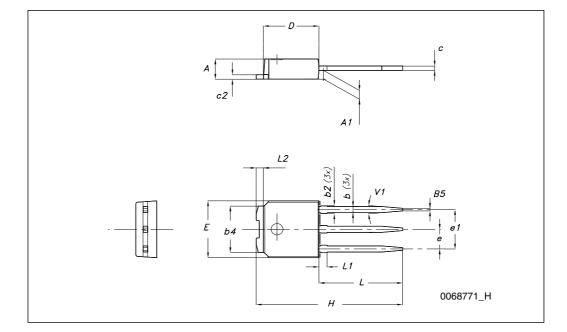


# 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

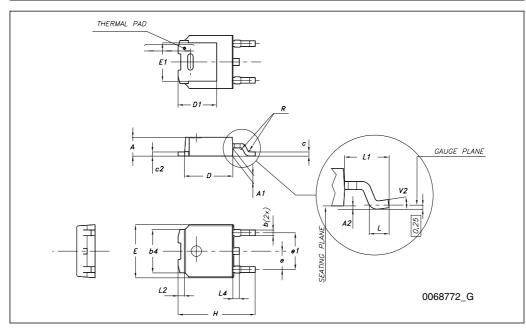


	TO-251 (IPAK) mechanical data				
DIM.		mm.			
	min.	typ	max.		
A	2.20		2.40		
A1	0.90		1.10		
b	0.64		0.90		
b2			0.95		
b4	5.20		5.40		
с	0.45		0.60		
c2	0.48		0.60		
D	6.00		6.20		
E	6.40		6.60		
е		2.28			
e1	4.40		4.60		
Н		16.10			
L	9.00		9.40		
(L1)	0.80		1.20		
L2		0.80			
V1		10 °			



Γ

DIM.		mm.	
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 <sup>o</sup>

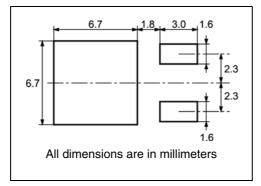


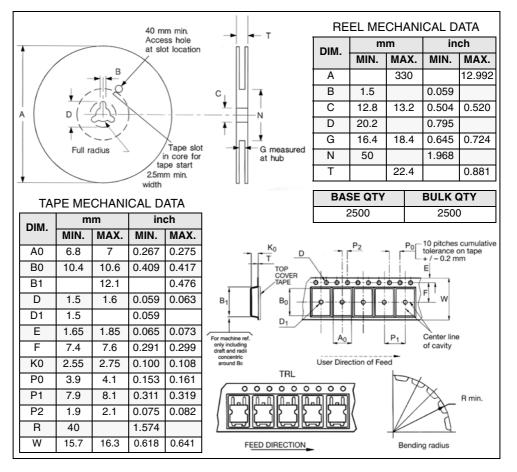
### TO-252 (DPAK) mechanical data

57

# 5 Packing mechanical data

### **DPAK FOOTPRINT**





#### **TAPE AND REEL SHIPMENT**

# 6 Revision history

### Table 7.Document revision history

Date	Revision	Changes
21-Jun-2004	3	Complete version
20-Jul-2006	4	New template, no content change
16-Sep-2008	5	Corrected part number: STU6NF10
19-Nov-2008	6	Marking label in <i>Table 1</i> for the device in IPAK has been updated. I <sub>GSS</sub> value in <i>Table 4</i> has been updated



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